
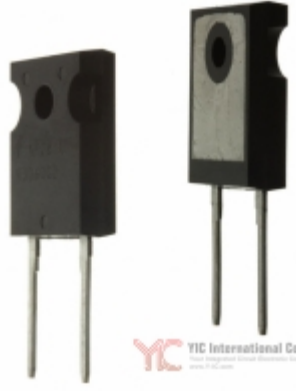
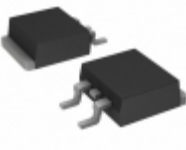



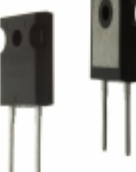



	<h2>ISL9R30120G2</h2>
	<p>Hersteller-Teilenummer: ISL9R30120G2</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: DIODE GEN PURP 1.2KV 30A TO247</p> <p>Datenblätter:  ISL9R30120G2.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 1332 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	ISL9R30120G2
Hersteller	Fairchild/ON Semiconductor
Beschreibung	DIODE GEN PURP 1.2KV 30A TO247
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	1332 pcs Stock
Serie	Stealth™
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-247-2
Supplier Device-Gehäuse	TO-247-2
Diodentyp	Standard
Strom - Richt (Io)	30A
Spannung - Forward (Vf) (Max) @ If	3.3V @ 30A
Strom - Sperrleckstrom @ Vr	100µA @ 1200V
Spannung - Sperr (Vr) (max)	1200V (1.2kV)
Geschwindigkeit	Fast Recovery = 200mA (Io)
Rückwärts-Erholzeit (Trr)	100ns
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	-
Verpackung	Tube

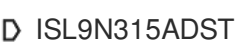
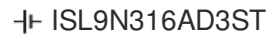
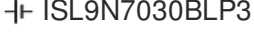
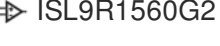


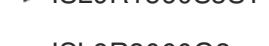
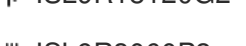








ISL9R30120G2 ist neu im Original, Suche ISL9R30120G2 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie ISL9R30120G2 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage ISL9R30120G2: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>ISL9R18120S3ST Fairchild/ON Semiconductor DIODE GEN PURP 1.2KV 18A TO263-2</p>	 <p>ISL9R2480G2 FAIRCHILD ISL9R2480G2 FAIRCHILD</p>	 <p>ISL9R3060G2 AMI Semiconductor / ON Semiconductor DIODE GEN PURP 600V 30A TO247</p>	 <p>ISL9R30120G2 AMI Semiconductor / ON Semiconductor DIODE GEN PURP 1.2KV 30A TO247</p>
 <p>ISL9R3060G2 Fairchild/ON Semiconductor DIODE GEN PURP 600V 30A TO247</p>	 <p>ISL9R3060P2 Fairchild/ON Semiconductor DIODE GEN PURP 600V 30A TO220AC</p>	 <p>ISL9R18120S3ST AMI Semiconductor / ON Semiconductor DIODE GEN PURP 1.2KV 18A TO263-2</p>	 <p>ISL9R3060G2-F085 AMI Semiconductor / ON Semiconductor DIODE GEN PURP 600V 30A TO247-2</p>

heiße Teile

Mehr

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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